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(71) Applicant (for all designated States except US): **SHARP  
KABUSHIKI KAISHA** [JP/JP]; 22-22, Nagaike-cho,  
Abeno-ku, Osaka-shi, Osaka 545-8522 (JP).

(72) Inventors; and

(75) Inventors/Applicants (for US only): **FUJII, Akiyoshi**  
[JP/JP]; 2-17, Sakyo 3-chome, Nara-shi, Nara 631-0801

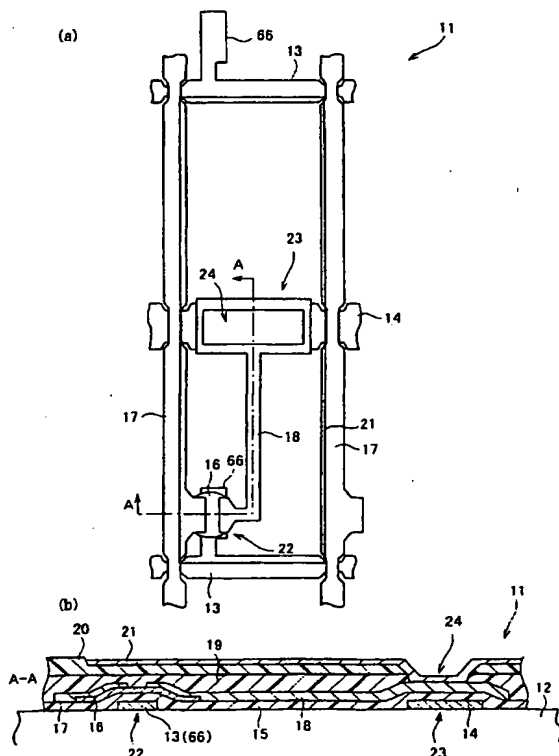
(JP). **NAKABAYASHI, Takaya** [JP/JP]; 1357, Kawan-  
ishi, Iga-cho, Ayama-gun, Mie 519-1425 (JP). **OCHI,**  
**Hisao** [JP/JP]; 2613-1, Ichinmoto-cho, Tenri-shi, Nara  
632-0004 (JP). **HARA, Takeshi** [JP/JP]; 4-2-10, Mi-  
dorigaoka, Heguri-cho, Ikoma-gun, Nara 636-0941 (JP).  
**SAITOH, Yuhichi** [JP/JP]; 2613-1, Ichinmoto-cho,  
Tenri-shi, Nara 632-0004 (JP).

(74) Agents: **HARA, Kenzo et al.**; HARAKENZO PATENT  
LAW FIRM, Daiwa Minamimorimachi Building, 2-6,  
Tenjinbashi 2-chome Kita, Kita-ku, Osaka-shi, Osaka  
530-0041 (JP).

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(54) Title: TFT ARRAY SUBSTRATE, LIQUID CRYSTAL DISPLAY DEVICE, MANUFACTURING METHODS OF TFT AR-  
RAY SUBSTRATE AND LIQUID CRYSTAL DISPLAY DEVICE, AND ELECTRONIC DEVICE



(57) Abstract: A TFT array substrate includes a thin film transi-  
stor section in which a gate electrode is formed on a substrate, and a  
semiconductor layer is formed on the gate electrode via a gate in-  
sulation layer. The semiconductor layer of this TFT array substrate  
has a shape formed by dropping a droplet. Accordingly, it is possi-  
ble to directly forming a semiconductor layer, or a resist layer for  
forming the semiconductor layer, by dropping a droplet(s). On this  
account, the present invention allows the use of an inkjet method,  
thus reducing costs and numbers of manufacturing processes.